

# HA31005ANP

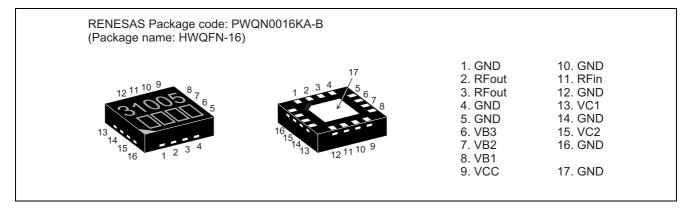
SiGe MMIC High Frequency Power Amplifier

> REJ03F0173-0200 Rev.2.00 Jul 31, 2007

#### Features

- Ideal for IEEE802.11a / b / g / n applications. e.g. Wireless LAN FEM
- High Gain (24 dB @ 5.2 GHz, 30dB @ 2.4 GHz)
- Small footprint package.
- (HWQFN-16 : 3.0 x 3.0 x 0.8 mm)
- RoHS Compliant

#### Outline



#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Supply Voltage	V <sub>CC</sub>	4	V
Maximum Current	I <sub>CC</sub>	400	mA
Maximum Input Power	P <sub>in max</sub>	+10	dBm
Total Power Dissipation	Pt	1.4 <sup>note</sup>	W
Operating Case Temperature	Tc(op)	-10 to +85	°C
Storage Temperature	Tstg	-55 to +150	°C

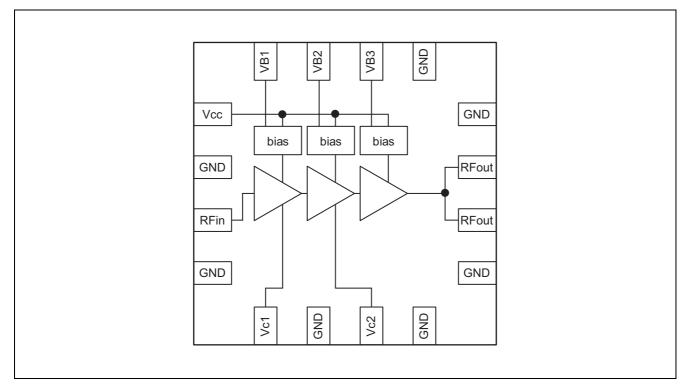
Notes: Value on PCB (FR-4 : 20 x 20 x 0.4 mm double side)

### **Electrical Characteristics**

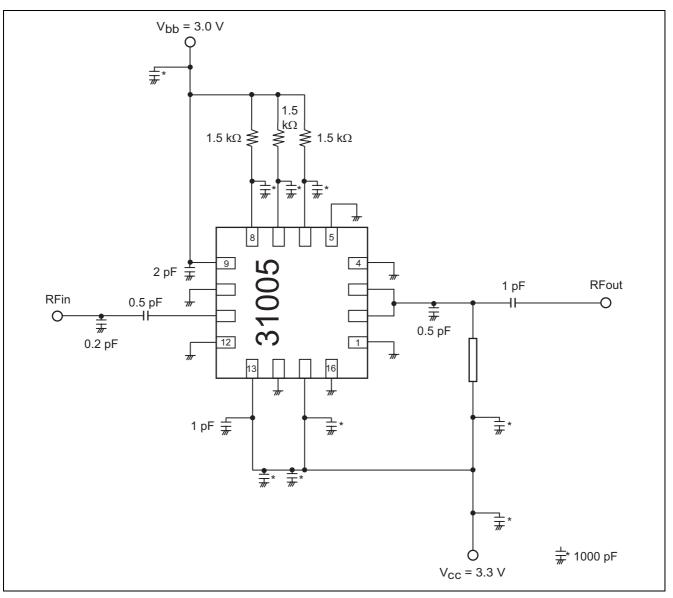
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min.	Тур	Max.	Unit	Test Conditions
Supply Voltage	V <sub>cc</sub>	3	3.3	3.6	V	
Power Gain	PG1		24	—	dB	f = 5.15 to 5.35 GHz
Circuit Current	lcc1		160	—	mA	Pout = +18 dBm, lcq = 130 mA
Output Power	Pout1	_	+18	—	dBm	f = 5.15 GHz , EVM = 4%, 54 Mbps, 64 QAM_OFDM, Icq = 130 mA
Power Gain	PG2		30	—	dB	f = 2.484 GHz
Circuit Current	lcc2		110	—	mA	Pout = +18 dBm, lcq = 90 mA
Output Power	Pout2	_	+18	—	dBm	f = 2.484 GHz, EVM = 4%, 54 Mbps, 64 QAM_OFDM, Icq = 90 mA
Power Gain	PG3		30	—	dB	f = 2.484 GHz, .11 b 11 Mbps
Circuit Current	Icc3	—	170	_	mA	Vcc = 3.3 V, Icq = 90 mA
Output Power	Pout3	_	+22	_	dBm	

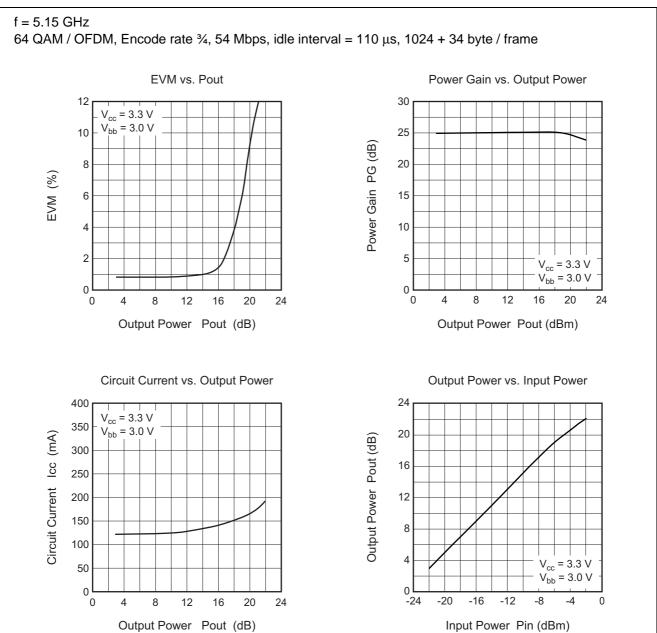
# **Function Block Diagram**



### **Evaluation Circuit for IEEE 802.11a**

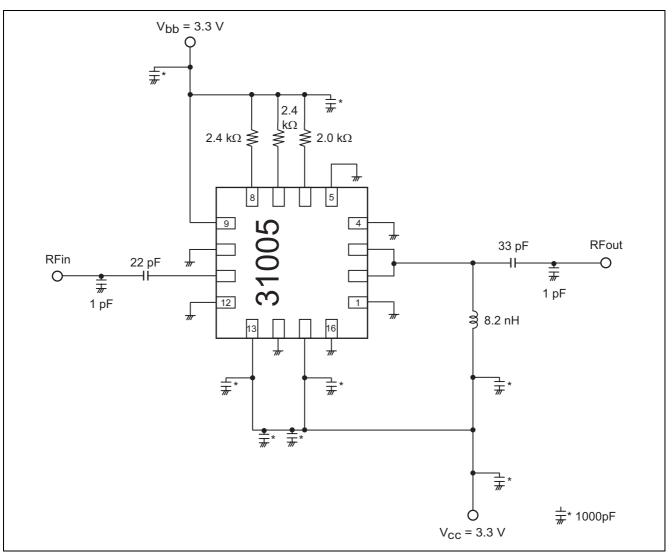


### **Characteristics for IEEE 802.11a**



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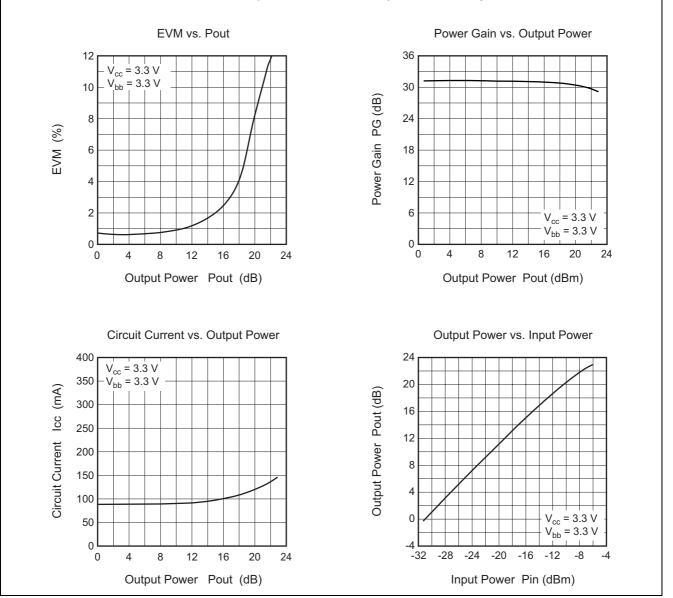
# **Evaluation Circuit for IEEE 802.11g**



#### Characteristics for IEEE 802.11g

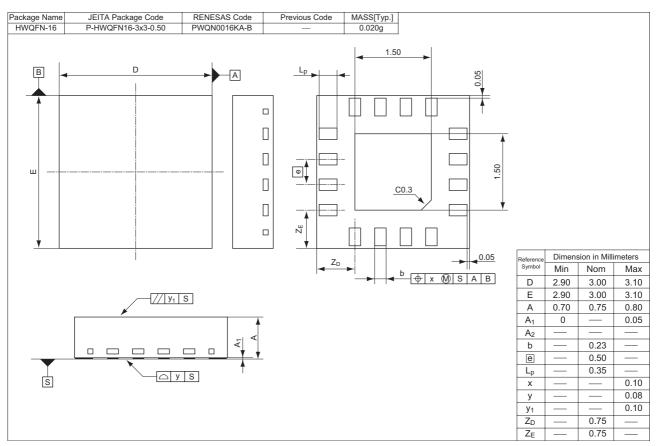


64 QAM / OFDM, Encode rate <sup>3</sup>/<sub>4</sub>, 54 Mbps, idle interval = 110 μs, 1024 + 34 byte / frame

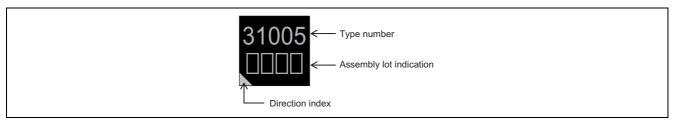


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### **Package Dimensions**



### Marking



### **Ordering Information**

Part No.	Quantity	Shipping Container
HA31005ANPTL-E	2000 pcs.	φ178 mm reel, 12 mm emboss taping

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